

DATA SHEET

SS1003EJ - Schottky Barrier Diode

30V, 1A Rectifier

Applications

• High frequency rectification (switching regulators, converters, choppers).

Features

- · Low switching noise.
- Low forward voltage (IF=500mA, VF max=0.39V) (IF=1A, VF max=0.45V).
- Ultraminiature (1608 size) and thin (0.6mm) leadless package.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|--|--------|-------------------------|-------------|------|
| Repetitive Peak Reverse Voltage | VRRM | | 30 | V |
| Nonrepetitive Peak Reverse Surge Voltage | VRSM | | 35 | V |
| Average Output Current | IO | | 1 | A |
| Surge Forward Current | IFSM | 50Hz sine wave, 1 cycle | 5 | A |
| Junction Temperature | Tj | | -55 to +125 | °C |
| Storage Temperature | Tstg | | -55 to +125 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---------------------------|------------------|--|---------|-----|------|--------|
| | | | min | typ | max | Unit |
| Reverse Voltage | VR | IR=500μA | 30 | | | V |
| Forward Voltage | V _F 1 | IF=500mA | | | 0.39 | V |
| | V _F 2 | IF=1A | | | 0.45 | V |
| Reverse Current | IR | V _R =15V | | | 360 | μΑ |
| Interterminal Capacitance | С | V _R =10V, f=1MHz | | 27 | | pF |
| Reverse Recovery Time | trr | IF=IR=10mA, See specified Test Circuit. | | | 10 | ns |
| Thermal Resistance | Rth(j-a) | Mounted on a ceramic board (600mm ² X0.8mm) | | 165 | | °C / W |

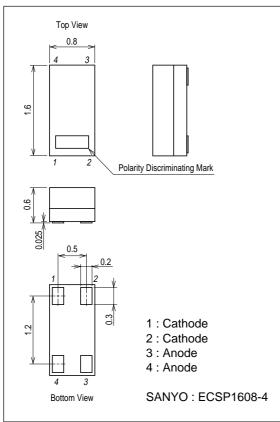
Marking : DH

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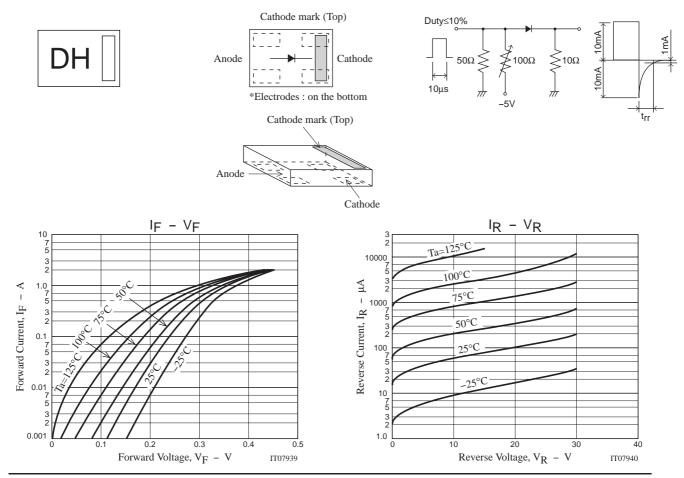
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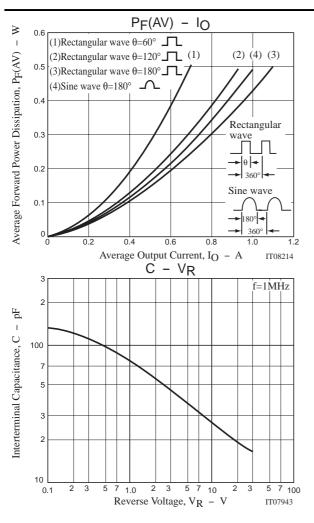
Package Dimensions

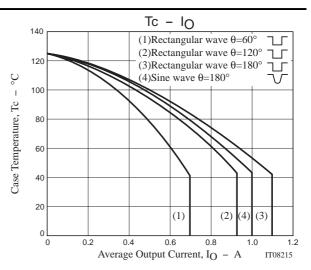
unit : mm (typ) 7033A-001



Type No. Indication (Top view) Electrical Connection (Top view) trr Test Circuit







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